AiP74LVC3G34
Triple Buffer

Product Specification

Specification Revision History:

Version	Date	Description
2017-04-A1	2017-04	New
2023-04-B1	2023-04	Update the template

Contents

1、General Description

The AiP74LVC3G34 provides three buffers.

The inputs can be driven from either 3.3V or 5V devices. This feature allows the use of the AiP74LVC3G34 as a translator in a mixed 3.3V and 5V environment.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- 5V tolerant input/output for interfacing with 5V logic
- ±24mA output drive (V_{CC}=3.0V)
- CMOS low power consumption
- Direct interface with TTL levels
- Specified from -40℃ to +125℃
- Packaging information:TSSOP8/VSSOP8

Ordering Information:

Tube packing specifications:

Part number	Packaging form	Marking code	Tube quantity	Boxed tube quantity	Boxed quantity	Notes
AiP74LVC3G34TA8.TB	TSSOP8	DCXX	100 PCS/tube	200 tube/box	20000 PCS/box	Dimensions of plastic enclosure: 3.0mm×3.0mm Pin spacing: 0.65mm

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
AiP74LVC3G34TA8.TR	TSSOP8	DCXX	3000 PCS/reel	3000 PCS/box	Dimensions of plastic enclosure: 3.0mm×3.0mm Pin spacing:0.65mm
AiP74LVC3G34YA8.TR	VSSOP8	DCXX	3000 PCS/reel	3000 PCS/box	Dimensions of plastic enclosure: 2.0mm×2.3mm Pin spacing:0.50mm

Note 1: “XX” refers to variable content, meaning year and package batch serial number.

Note 2: If the physical information is inconsistent with the ordering information, please refer to the actual product.

2、Block Diagram And Pin Description

2.1、Block Diagram

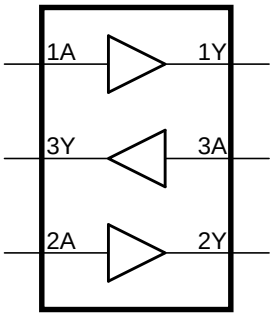


Figure 1. Logic symbol

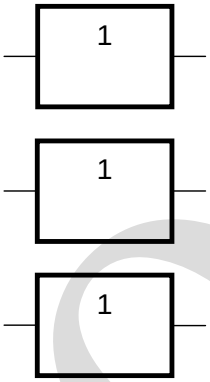
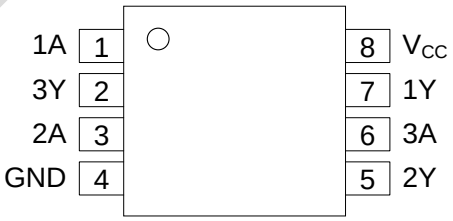


Figure 2. IEC logic symbol

Figure 3. Logic diagram (one gate)

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	1A	data input
2	3Y	data output
3	2A	data input
4	GND	ground (0V)
5	2Y	data output
6	3A	data input
7	1Y	data output
8	V_{CC}	supply voltage

2.4、Function Table

Input	Output
nA	**nY**
L	L
H	H

Note: H=HIGH voltage level; L=LOW voltage level

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(T_{amb}=25℃, All voltage referenced to GND, unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input clamping current	I_{IK}	V_I<0V	-50	-	mA
input voltage	V_I	-[1]	-0.5	+6.5	V
output clamping current	I_{OK}	V_O>V_{CC} or V_O<0V	-	±50	mA
output voltage	V_O	Active mode[1]	-0.5	V_{CC}+0.5	V
		Power-down mode[1]	-0.5	+6.5	V
output current	I_O	V_O=0V to V_{CC}	-	±50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	℃
total power dissipation	P_{tot}	-	-	250	mW
soldering temperature	T_L	10s	260		℃

Note:

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; V_{CC}=0V	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+125	℃
input transition rise and fall rate	Δt/ΔV	V_{CC}=1.65V to 2.7V	-	-	20	ns/V
		V_{CC}=2.7V to 5.5V	-	-	10	ns/V

3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

(T_{amb}=-40℃ to +85℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.[1]	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=1.65V to 1.95V		0.65× V_{CC}	-	-	V
		V_{CC}=2.3V to 2.7V		1.7	-	-	V
		V_{CC}=2.7V to 3.6V		2.0	-	-	V
		V_{CC}=4.5V to 5.5V		0.7× V_{CC}	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=1.65V to 1.95V		-	-	0.35× V_{CC}	V
		V_{CC}=2.3V to 2.7V		-	-	0.7	V
		V_{CC}=2.7V to 3.6V		-	-	0.8	V
		V_{CC}=4.5V to 5.5V		-	-	0.3× V_{CC}	V
HIGH-level output voltage	V_{OH}	V_I=V_{IH} or V_{IL}	I_O=-100uA; V_{CC}=1.65V to 5.5V	V_{CC}-0.1	-	-	V
			I_O=-4mA; V_{CC}=1.65V	1.2	-	-	V
			I_O=-8mA; V_{CC}=2.3V	1.9	-	-	V
			I_O=-12mA; V_{CC}=2.7V	2.2	-	-	V
			I_O=-24mA; V_{CC}=3.0V	2.3	-	-	V
			I_O=-32mA; V_{CC}=4.5V	3.8	-	-	V
LOW-level output voltage	V_{OL}	V_I=V_{IH} or V_{IL}	I_O=100uA; V_{CC}=1.65V to 5.5V	-	-	0.10	V
			I_O=4mA; V_{CC}=1.65V	-	-	0.45	V
			I_O=8mA; V_{CC}=2.3V	-	-	0.30	V
			I_O=12mA; V_{CC}=2.7V	-	-	0.40	V
			I_O=24mA; V_{CC}=3.0V	-	-	0.55	V
			I_O=32mA; V_{CC}=4.5V	-	-	0.55	V
input leakage current	I_I	V_I=5.5V or GND; V_{CC}=0V to 5.5V		-	-	±1	uA
power-off leakage current	I_{OFF}	V_I or V_O=5.5V; V_{CC}=0V		-	-	±2	uA

supply current	I_{CC}	V_I=5.5V or GND; I_O=0A; V_{CC}=1.65V to 5.5V	-	-	4	uA
additional supply current	ΔI_{CC}	per pin; V_I=V_{CC}-0.6V; I_O=0A; V_{CC}=2.3V to 5.5V	-	-	500	uA
input capacitance	C_I	V_{CC}=3.3V; V_I=GND to V_{CC}	-	2.5	-	pF

Note: All typical values are measured at V_{CC}=3.3V and T_{amb}=25℃.

3.3.2、DC Characteristics 2

(T_{amb}=-40℃ to +125℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.[1]	Max.	Unit
HIGH-level input voltage	V_{IH}	V_{CC}=1.65V to 1.95V		0.65× V_{CC}	-	-	V
		V_{CC}=2.3V to 2.7V		1.7	-	-	V
		V_{CC}=2.7V to 3.6V		2.0	-	-	V
		V_{CC}=4.5V to 5.5V		0.7× V_{CC}	-	-	V
LOW-level input voltage	V_{IL}	V_{CC}=1.65V to 1.95V		-	-	0.35× V_{CC}	V
		V_{CC}=2.3V to 2.7V		-	-	0.7	V
		V_{CC}=2.7V to 3.6V		-	-	0.8	V
		V_{CC}=4.5V to 5.5V		-	-	0.3× V_{CC}	V
HIGH-level output voltage	V_{OH}	V_I=V_{IH} or V_{IL}	I_O=-100uA; V_{CC}=1.65V to 5.5V	V_{CC}-0.1	-	-	V
			I_O=-4mA; V_{CC}=1.65V	0.95	-	-	V
			I_O=-8mA; V_{CC}=2.3V	1.7	-	-	V
			I_O=-12mA; V_{CC}=2.7V	1.9	-	-	V
			I_O=-24mA; V_{CC}=3.0V	2.0	-	-	V
			I_O=-32mA; V_{CC}=4.5V	3.4	-	-	V
LOW-level output voltage	V_{OL}	V_I=V_{IH} or V_{IL}	I_O=100uA; V_{CC}=1.65V to 5.5V	-	-	0.10	V
			I_O=4mA; V_{CC}=1.65V	-	-	0.70	V
			I_O=8mA; V_{CC}=2.3V	-	-	0.45	V
			I_O=12mA; V_{CC}=2.7V	-	-	0.60	V
			I_O=24mA; V_{CC}=3.0V	-	-	0.80	V
			I_O=32mA; V_{CC}=4.5V	-	-	0.80	V
input leakage current	I_I	V_I=5.5V or GND; V_{CC}=0V to 5.5V		-	-	±1	uA
power-off leakage current	I_{OFF}	V_I or V_O=5.5V; V_{CC}=0V		-	-	±2	uA
supply current	I_{CC}	V_I=5.5V or GND; I_O=0A; V_{CC}=1.65V to 5.5V		-	-	4	uA
additional supply current	ΔI_{CC}	per pin; V_I=V_{CC}-0.6V; I_O=0A; V_{CC}=2.3V to 5.5V		-	-	500	uA

Note: All typical values are measured at V_{CC}=3.3V and T_{amb}=25℃.

3.3.3、AC Characteristics 1

(T_{amb}=-40℃ to +85℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.[1]	Max.	Unit
nA to nY propagation delay	t_{pd}	see Figure 5[2]	V_{CC}=1.65V to 1.95V	1.0	3.8	8.6	ns
			V_{CC}=2.3V to 2.7V	0.5	2.4	4.4	ns
			V_{CC}=2.7V	0.5	2.5	5.0	ns
			V_{CC}=3.0V to 3.6V	0.5	2.2	4.1	ns
			V_{CC}=4.5V to 5.5V	0.5	1.9	3.2	ns
power dissipation capacitance	C_{PD}	V_{CC}=3.3V; V_I=GND to V_{CC}[3]		-	14	-	pF

Note:

[1] Typical values are measured at T_{amb}=25℃ and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$P_D=C_{PD}\times V_{CC}^2\times f_i\times N+\sum(C_L\times V_{CC}^2\times f_o)$ where:

f_i=input frequency in MHz;

f_o=output frequency in MHz;

C_L=output load capacitance in pF;

V_{CC}=supply voltage in V;

N=number of inputs switching;

$\sum(C_L\times V_{CC}^2\times f_o)$=sum of outputs.

3.3.4、AC Characteristics 2

(T_{amb}=-40℃ to +125℃, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.[1]	Max.	Unit
nA to nY propagation delay	t_{pd}	see Figure 5[2]	V_{CC}=1.65V to 1.95V	1.0	-	10.8	ns
			V_{CC}=2.3V to 2.7V	0.5	-	5.5	ns
			V_{CC}=2.7V	0.5	-	6.3	ns
			V_{CC}=3.0V to 3.6V	0.5	-	5.1	ns
			V_{CC}=4.5V to 5.5V	0.5	-	4.0	ns

Note:

[1] Typical values are measured at T_{amb}=25℃ and V_{CC}=1.8V, 2.5V, 2.7V, 3.3V and 5.0V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

4、Testing Circuit

4.1、AC Testing Circuit

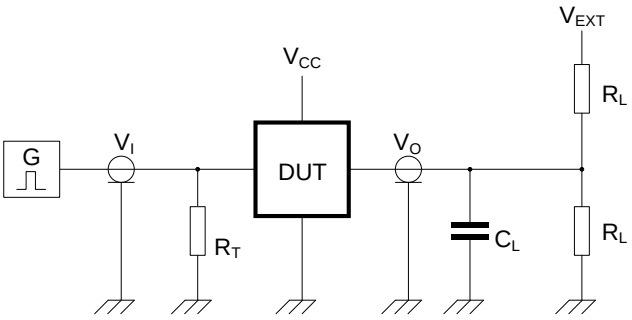


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L=Load resistance.

C_L=Load capacitance including jig and probe capacitance.

R_T=Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT}=External voltage for measuring switching times.

4.2、AC Testing Waveforms

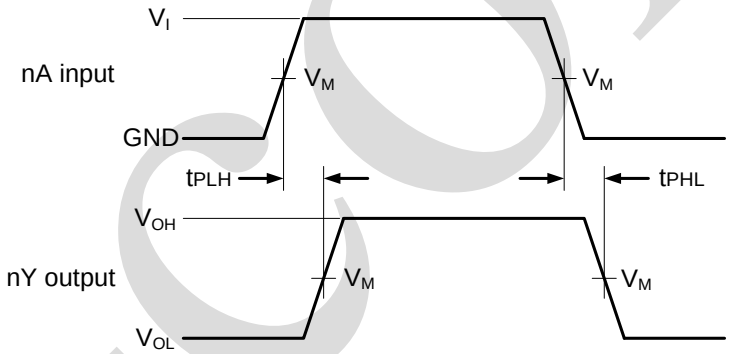


Figure 5. The input nA to output nY propagation delays

4.3、Measurement Points

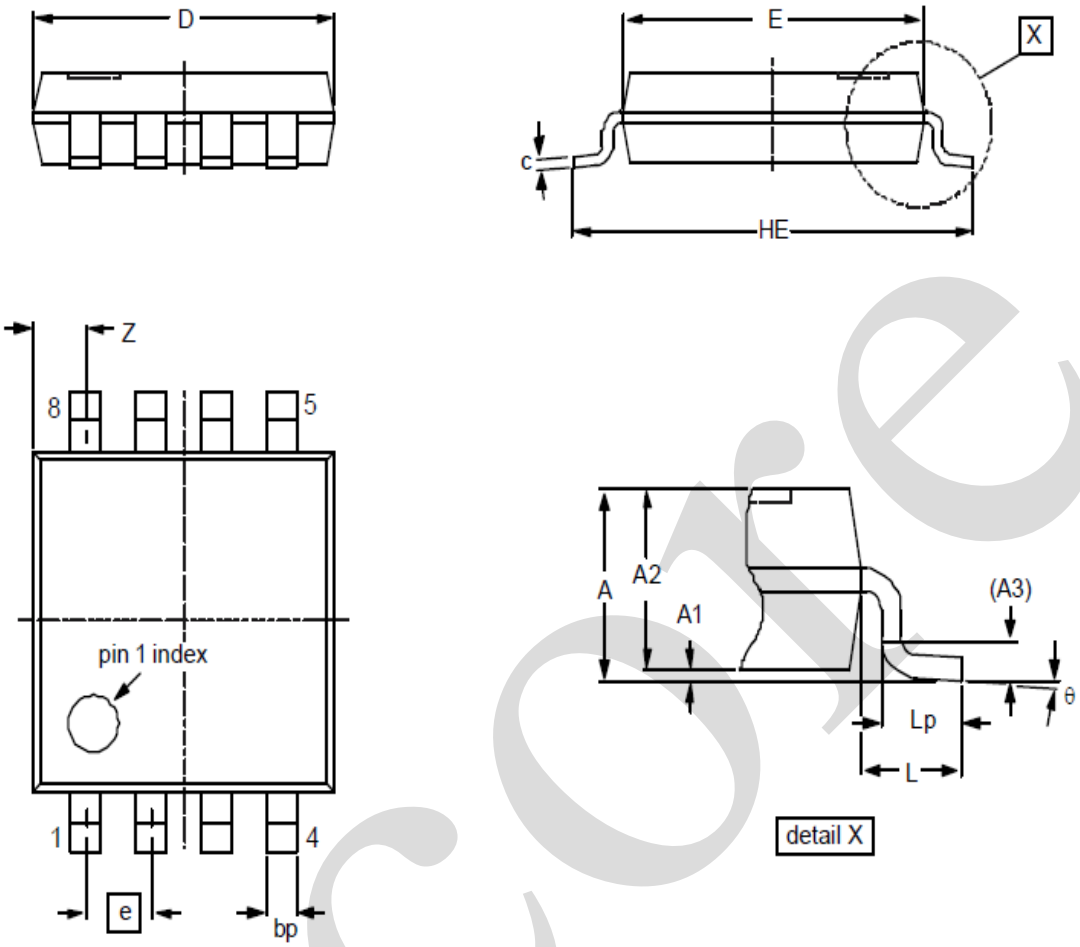
Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5\times V_{CC}$	$0.5\times V_{CC}$
2.3V to 2.7V	$0.5\times V_{CC}$	$0.5\times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5\times V_{CC}$	$0.5\times V_{CC}$

4.4、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r=t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65V to 1.95V	V_{CC}	≤2.0ns	30pF	1kΩ	open
2.3V to 2.7V	V_{CC}	≤2.0ns	30pF	500Ω	open
2.7V	2.7V	≤2.5ns	50pF	500Ω	open
3.0V to 3.6V	2.7V	≤2.5ns	50pF	500Ω	open
4.5V to 5.5V	V_{CC}	≤2.5ns	50pF	500Ω	open

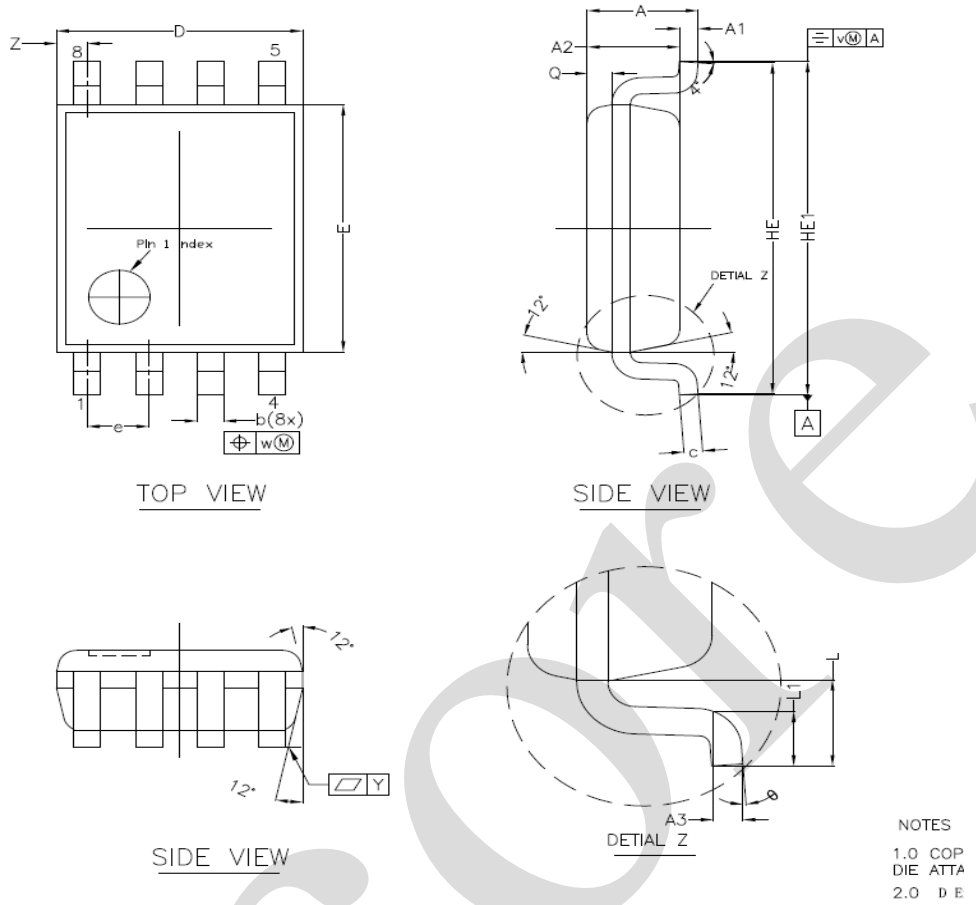
5、Package Information

5.1、TSSOP8



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.10
A1	0	0.15
A2	0.75	0.95
A3	0.25	
bp	0.22	0.38
c	0.08	0.18
D	2.90	3.10
E	2.90	3.10
HE	3.90	4.10
L	0.50	
Lp	0.33	0.47
e	0.65	
Z	0.35	0.70
θ	0°	8°

5.2、VSSOP8



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.00
A1	0.00	0.15
A2	0.60	0.85
A3	0.12	
Q	0.19	0.21
b	0.17	0.27
c	0.08	0.23
D	1.90	2.10
E	2.20	2.40
HE	3.00	3.20
e	0.50	
L	0.40	
L1	0.15	0.40
Y	0.10	
Z	0.10	0.40
θ	0°	8°

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○：Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×：Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									

6.2、Notes

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